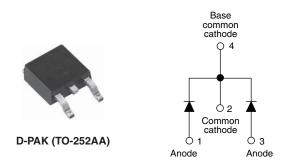
Vishay Semiconductors

# High Performance Schottky Rectifier, 2 x 6 A



PRODUCT SUMMARY							
Package	D-PAK (TO-252AA)						
I <sub>F(AV)</sub>	2 x 6 A						
V <sub>R</sub>	60 V						
$V_F$ at $I_F$	0.57 V						
I <sub>RM</sub>	35 mA at 125 °C						
T <sub>J</sub> max.	150 °C						
Diode variation	Common cathode						
E <sub>AS</sub>	7 mJ						

## **FEATURES**

- Popular D-PAK outline
- Center tap configuration
- · Small foot print, surface mountable
- · Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### DESCRIPTION

The VS-12CWQ06FNPbF surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS A V A V						
I <sub>F(AV)</sub>	Rectangular waveform	12	А						
V <sub>RRM</sub>		60	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	320	А						
V <sub>F</sub>	6 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.57	V						
TJ	Range	-55 to +150	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-12CWQ06FNPbF	UNITS						
Maximum DC reverse voltage	V <sub>R</sub>	60	V						
Maximum working peak reverse voltage	V <sub>RWM</sub>	80	v						

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMB	OL	TEST CONDI	VALUES	UNITS				
Maximum average	ber leg		50 % duty avala at $T_{a} = 131 $ °C	6	А				
	device	$I_{F(AV)}$ 50 % duty cycle at $T_C$ = 131 °C, rectangular waveform				A			
Maximum peak one cycle non-repetitive surge current			5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	320	А			
See fig. 7	IFSM	IFSM 10 ms sine or 6 ms rect. pulse		rated $V_{RRM}$ applied	105	~			
Non-repetitive avalanche energy per leg		5	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.2 A, L = 10 mH		7	mJ			
Repetitive avalanche current per leç	g I <sub>AR</sub>		Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>B</sub> typical		0.8	А			

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS					
		6 A	T <sub>.1</sub> = 25 °C	0.61	V				
Maximum forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	12 A	1j=23 0	0.79					
See fig. 1	VFM (*)	6 A	T.I = 125 °C	0.57					
		12 A	1j = 125 0	0.72					
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B} = \text{Rated } V_{\rm B}$	3	mA				
See fig. 2	IRM \''	T <sub>J</sub> = 125 °C	VR - naleu VR	35	ША				
Threshold voltage	V <sub>F(TO)</sub>	T. T. M. M.		0.36	V				
Forward slope resistance	r <sub>t</sub>	$T_J = T_J maximum$	24.14	mΩ					
Typical junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ , (test signal ran	360	pF					
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 m	5.0	nH					

### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

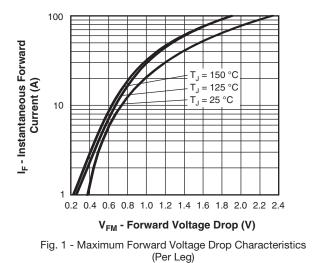
THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range		$T_{J}$ <sup>(1)</sup> , $T_{Stg}$		-55 to +150	°C				
Maximum thermal resistance,	per leg	P	DC operation	3.0	°C/W				
junction to case	per device	R <sub>thJC</sub>	See fig. 4	1.5	0/11				
				0.3	g				
Approximate weight				0.01	oz.				
Marking device			Case style D-PAK (similar to TO-252AA)	12CW0	Q06FN				

### Note

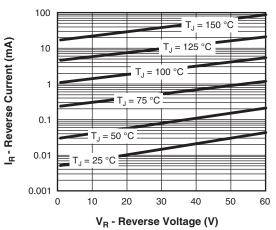
(1)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

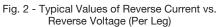
# VS-12CWQ06FNPbF

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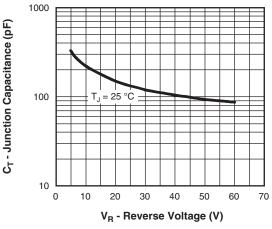


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

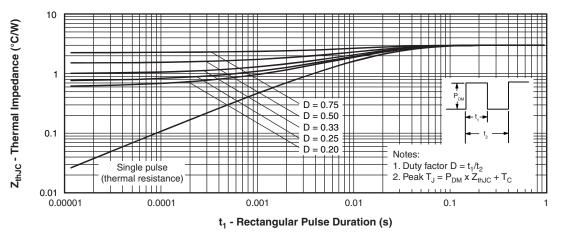
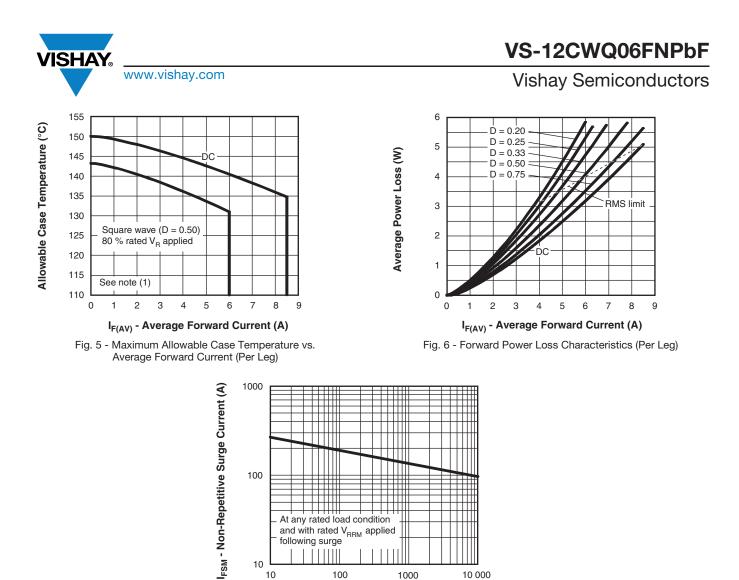


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)



tp - Square Wave Pulse Duration (µs)

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

### Note

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<sup>(1)</sup> Formula used: T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC};

Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D) (see fig. 6);

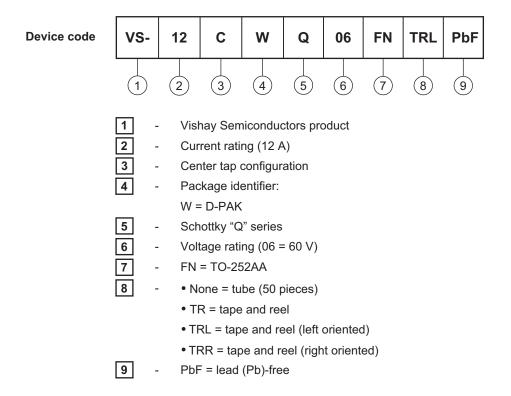
Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D); I_R at V_{R1} = 80 \% rated V_R
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**ORDERING INFORMATION TABLE** 

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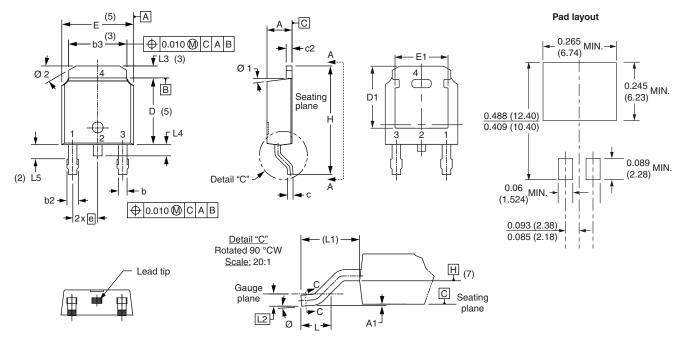
LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95016						
Part marking information	www.vishay.com/doc?95059						
Packaging information	www.vishay.com/doc?95033						
SPICE model	www.vishay.com/doc?95278						





D-PAK (TO-252AA)

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	INCHES		NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

(2) Lead dimension uncontrolled in L5

<sup>(3)</sup> Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(6)</sup> Dimension b1 and c1 applied to base metal only

<sup>(7)</sup> Datum A and B to be determined at datum plane H

<sup>(8)</sup> Outline conforms to JEDEC outline TO-252AA

1



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